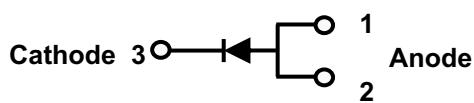


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**Features**

- Advanced trench technology
- Low forward voltage drop
- Low power losses
- High efficiency operation
- Lead Free Finish, RoHS Compliant

Applications

- DC/DC Converters
- AC/DC Adaptors
- Switching Power Supplies
- Freewheeling Diodes

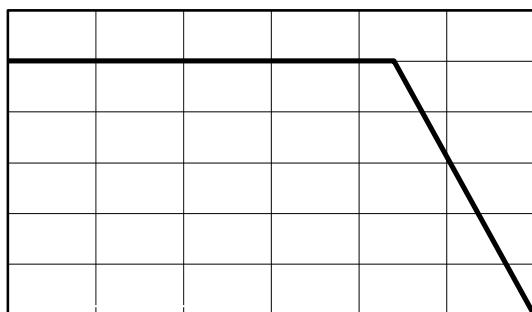
Maximum ratings and electrical characteristics (TJ = 25°C unless otherwise noted)

Parameter	Symbol	Limit		Unit
Maximum repetitive peak reverse voltage	VRRM			V
Maximum average forward rectified current	IF(AV)			A
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	IFSM	0		A
Operating junction and storage temperature range	TJ, TSTG	-40 to +150		°C
Typical thermal resistance per diode(Mounted on FR-4 PCB)	R _{JC}	72		°C/W
Instantaneous forward voltage per diode	VF(1)	TYP.	MAX.	
		0.51	0.56	V
		0.46	-	
		0.89	5	
		0.82	-	
Instantaneous reverse current per diode at rated reverse voltage	IR(2)	50		uA
		5	-	mA

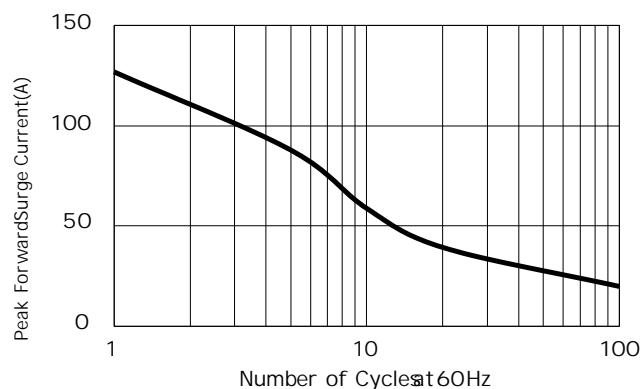
Notes:

(1) Pulse test: 300 μs pulse width, 1 A duty cycle

(2) Pulse test: Pulse width 0 ~ 100 μs

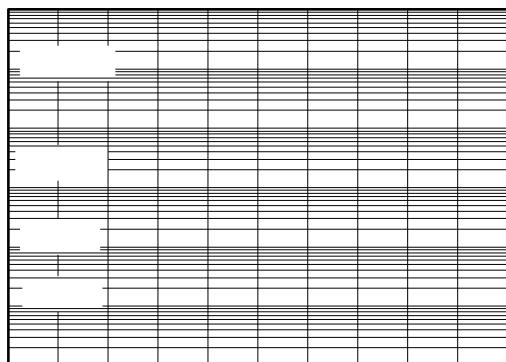
RATINGS AND CHARACTERISTICS CURVES (TA = 25 °C unless otherwise noted)7 F & D V H^R&7 H P S

Current Derating, Case



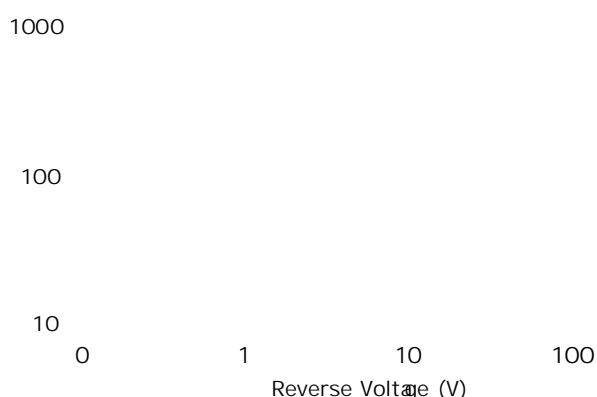
Maximum Repetitive Surge Current

Ir Reverse Current(μA)



955HYHUVH 9ROWDZH 9ROWV

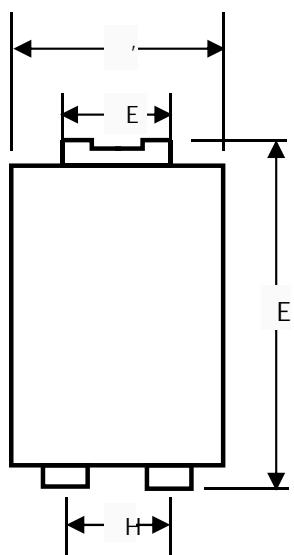
Typical Reverse Current



Typical Junction Capacitance 7M

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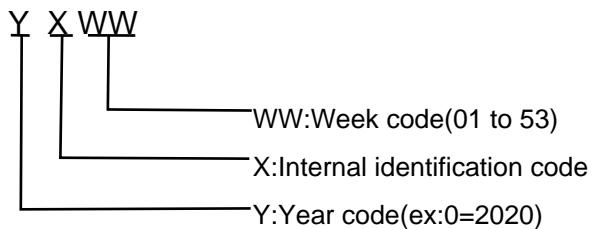
7 2



Marking Information

Product model :TSP5 6
to as 5 6

8PDC information



Packaging Information